

Image may be representation. See specifications for product details.

DS1250W-150

Part Number:

Manufacturer/Brand: Product description

Datasheets:

Ship From

RoHs Status

Shipment Way

DS1250W-150

Maxim Integrated

IC NVSRAM 4M PARALLEL 32EDIP

DS1250W-150.pdf

Contains lead / RoHS non-compliant

Hong Kong

DHL/Fedex/TNT/UPS/EMS

REQUEST FOR QUOTATION

PART NUMBER DS1250W-150 MANUFACTURER MANUFACTURER MEXIMATION MEXIMATE PARALLEL 32EDIP LEAD FREE STATUS / ROHS STATUS COTICIAIS lead / ROHS non-compliant DATA SHEET WITTE CYCLE TIME - WORD, PAGE VOLTAGE - SUPPLY TECHNOLOGY NAVSRAM (Non-Volatile SRAM) SUPPLIER DEVICE PACKAGE SERIES PACKAGING PACKAGING TUDE PACKAGING POPERATING TEMPERATURE MOUNTING TYPE MOUNTING TYPE MEMORY TYPE MEMORY TYPE MEMORY SIZE MEMORY SIZE MEMORY SIZE MEMORY FORMAT LEAD FREE STATUS / ROHS STATUS DS1250W ACCESS TIME BASE PART NUMBER MESCASS JUDE MEMORY ICAMBO (512K x 8) PACKAGING MEMORY FORMAT NAVSRAM (Non-Volatile SRAM) Memory IC 4Mb (512K x 8) Parallel 150ns 32-EDIP BASE PART NUMBER ACCESS TIME BASE PART NUMBER DS1250W ACCESS TIME BASE PART NUMBER DS1250W ACCESS TIME ACC		Specifications of DS1250W-150
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DETAILED DESCRIPTION NVSRAM (Non-Volatile SRAM) Memory IC 4Mb (512K x 8) Parallel 150ns 32-EDIP BASE PART NUMBER DS1250W	MEMORY FORMAT	NVSRAM
BASE PART NUMBER DS1250W	LEAD FREE STATUS / ROHS STATUS	Contains lead / RoHS non-compliant
	DETAILED DESCRIPTION	NVSRAM (Non-Volatile SRAM) Memory IC 4Mb (512K x 8) Parallel 150ns 32-EDIP
ACCESS TIME 150ns	BASE PART NUMBER	DS1250W
	ACCESS TIME	150ns

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DS1250Y-100 Manufacturers: Maxim Integrated

Description: IC NVSRAM 4M PARALLEL 32EDIP In stock: Out stock

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DS1250W-100IND+

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In stock: Out stock

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DS1250W-100+

Manufacturers: Maxim Integrated

Description: IC NVSRAM 4M PARALLEL 32EDIP In stock: 13 pcs

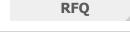
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DS1250WP-100IND+

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Description: IC NVSRAM 4M PARALLEL 34PWRCAP In stock: 80 pcs





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Description: IC NVSRAM 4M PARALLEL 32EDIP In stock: Out stock

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